Facility updates for high-resolution and high-accuracy crystallography

Ichiro Inoue & Kensuke Tono on behalf of SACLA beamline group





Motivation of this breakout session

Number of users employing high-photon energy XFEL beam (>15 keV) is gradually growing.

Many interesting outcomes in high-resolution crystallography are being published.



-> It's a good timing to learn about the latest researches in this field and discuss about future facility capabilities

Photon parameters compared to other XFEL facilities



SACLA is highly competitive in high-resolution and high-accuracy crystallography

Sub-10 fs pulses are definitely needed for accurate structure determination



Program

Introduction

15:00-15:20 Ichiro Inoue (SACLA) 'Facility updates for high-resolution and high-accuracy femtosecond crystallography'

Research highlights and requests to facility

15:20-16:20 Kiyofumi Takaba (RIKEN) 'Sub-Å resolution SACLA-SFX for organic chemicals'

Hidetaka Kasai (U. Tsukuba) 'Serial femtosecond crystallography for materials science and chemistry'

Hiroshi Sugimoto (RIKEN)

'Hydrogen atoms in protein structure: high resolution analysis of heme enzymes'

Discussion (chair: Kensuke Tono) 16:20-17:00

New standard configuration setup for high-resolution crystallography (2022B~)

Model Telestics (2023?)

Optics updates at BL2 (2022B~)

New standard configuration setup for high-resolution crystallography

Current standard configurations

w/ MPCCD (max 2θ: 48 deg)
Camera length: <u>50 mm</u>
Direct detection of X-ray photons

(Si 300 μm, can detect single photon)

Small sensor area: 110 mm X 110 mm



Sample injectors



MPCCD detector

Sample chamber Tono, JSR 22, 532 (2015)

w/ Rayonix 300-HS (max 2*θ*: 56 deg)
Camera length: <u>100 mm</u> or more
Large sensor area: 300 mm X 300 mm
Phosphor (Gd₂O₂S, 40 um thick) coupled CCD: good quantum efficiency at high photon energy (*cf.* 90%@15 keV)



Additional standard configurations (2022B~)

 w/ Rayonix 300-HS (max 2θ: 72 deg)
 camera length <u>50 mm</u> or more (changeable during beam time)



Resolution limit determined by the detector geometry: •0.88 Å @12 keV •0.70 Å @15 keV •0.54 Å @20 keV

cf. IUCr cif check: s>0.59 Å⁻¹, *i.e.*, *d*_{min} <0.85 Å

Detector development

Si-based direct illumination detector (CITIUS) will be introduced as a successor of MPCCD (probably next year for the 20.2 M variant, but the schedule has not been fixed yet due to the recent semiconductor crisis)

* MPCCD is available for a while, but will be replaced to CITIUS in a long term.

		Value			
Parameters		CITIUS XFEL for SACLA		MPCCD Phase III/III-L	Unit
	Thickness	650		x2.1 300	μm
	Pixel Size	72.6 µm		x1.5 50	μm
	Pixel Number	0.28		■ x0.6 0.5	Mpixel/sensor
Sensor	Image Format	384 x 728		512 x 1024	pixels
	Noise	60 e- or better		300/60	e-rms
	Peak Signal	17,000		x7 2,400	Phs.@ 6 keV
	Frame Rate	60 (max. 5 kHz)		60 or 30 Hz	
Largest System	Pixel Number	20.2 Mpixel		x 5 4	Mpixel
	Image Area	325 x 363		100 x 100	mm ²
Tiling	Inter-module gap	~ 3 mm		■ x3 < 1 mm	

CITIUS: Camera Head Variants (under development)

280k Compact



36 x 96 x 197 mm³ ~1 kg Fan-less operation is possible.





2.2M standard



SACLA goes to higher repetition operation in long term, MPCCD need to be replaced by CITIUS. However.

- not all the spec. will be better.
- replacement demands significant budget and internal resources. We would like to have user comments, especially, on
- Deployment Priority to CITIUS detector
- MPCCD detector not replaceable by CITIUS

We are finalizing deployment plan for FY2022-2023 by the end of April 2021.

- •Large sensor area (325 mm X 363 mm)
- •Single photon sensitivity
- •Large dynamic range
- Inter-module gap as large as 3 mm
- •Pixel size is a bit larger than that of MPCCD

Slides from Takaki Hatsui (RIKEN) SACLA Users' meeting 2021

Optics development for high photon energy operation (BL2)



Expand available photon energy range of BL2 by coating mirrors



High photon energy (up to 22 keV) will be available at BL2 from 2022B

cf. Specification of current mirror parameters

	Plane mirror for b Original	cam transport (a) Current
Mirror length	0.4 m	0.5 m (BL3)/0.6 m (BL2)
Glancing angle	4 mrad	4 mrad
Acceptance	1.6 mm	2.0 mm (BL3)/2.4 mm (BL2)
Coating	None (Si)	Rh/Si
Cutoff energy	7.5 keV	16 keV (Rh) /7.5 keV (Si)
	Plane mirror for b	eam transport (b)
	Original	Current
Mirror length	0.4 m	0.5 m (BL3)/0.6 m (BL2)
Glancing angle	2 mrad	2 mrad
Acceptance	0.8 mm	1.0 mm (BL3)/1.2 mm (BL2)
Coating	None (Si)	Rh/Si
Cutoff energy	15 keV	33 keV (Rh) /15 keV (Si)

Tono, Proc. SPIE 10237 (2017).

Facility update plans

Mew standard configuration setup for high-resolution crystallography (2022B~)

✓ Detector updates (2023?)

✓Optics updates at BL2 (2022B~)

-We would like to have feedback from users and any kinds of suggestions for moving high-resolution fs crystallography forward

-> Discussion part in this session